

LTC3450

Triple Output Power Supply for Small TFT-LCD Displays

FEATURES

- Generates Three Voltages: 5.1V at 10mA
 - J. IV at IUIIIA _5V _10 or _11
 - -5V, -10, or -15V at 500µA 10V or 15V at 500µA
- Better than 90% Efficiency
- Low Output Ripple: Less than 5mV_{P-P}
- Complete 1mm Component Profile Solution
- Controlled Power-Up Sequence: AV_{DD}/V_{GI}/V_{GH}
- All Outputs Disconnected and Actively Discharged in Shutdown
- Low Noise Fixed Frequency Operation
- Frequency Reduction Input for High Efficiency in Blank Mode
- Ultralow Quiescent Current: 75µA (Typ) in Scan Mode
- Available in a 3mm × 3mm 16-Pin QFN Package

APPLICATIONS

- Cellular Handsets with Color Display
- Handheld Instruments
- PDA

DESCRIPTION

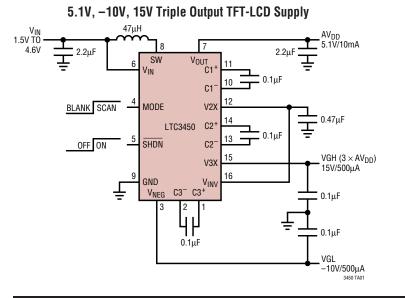
The LTC[®]3450 is a complete power converter solution for small thin film transistor (TFT) liquid crystal display (LCD) panels. The device operates from a single Lithium-Ion cell, 2- to 3-cell alkaline input or any voltage source between 1.5V and 4.6V.

The synchronous boost converter generates a low noise, high efficiency 5.1V, 10mA supply. Internal charge pumps are used to generate 10V, 15V, and -5V, -10V or -15V. Output sequencing is controlled internally to insure proper initialization of the LCD panel.

A master shutdown input reduces quiescent current to $<\!2\mu A$ and quickly discharges each output for rapid turn off of the LCD panel. The LTC3450 is offered in a low profile (0.8mm max), 3mm \times 3mm 16-pin QFN package, minimizing the solution profile and footprint.

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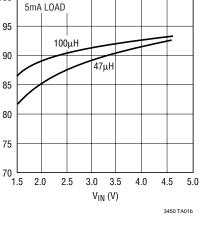
TYPICAL APPLICATION



AV_{DD} Efficiency vs V_{IN}

100

EFFICIENCY (%)

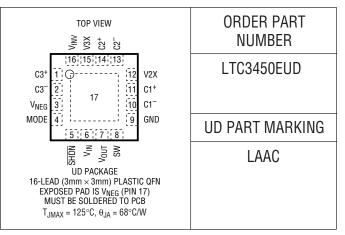


ABSOLUTE MAXIMUM RATINGS

(Note 1) (Referred to GND)

V _{IN} , SW	0.3 to 7V
SHDN, MODE	
V _{OUT}	0.3 to 7V
V _{NEG}	–17V to 0.3V
Operating Temperature Range	
LTC3450E (Note 4)	40°C to 85°C
Storage Temperature Range	–65°C to 125°C

PACKAGE/ORDER INFORMATION



Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. V_{IN} = 3.6V, V_{OUT} = 5.2V unless otherwise noted.

CONDITIONS		MIN	ТҮР	MAX	UNITS
	•	1.5		4.6	V
MODE = V _{IN}			75	130	μA
MODE = V _{IN}			80		μA
MODE = GND			30	50	μA
MODE = GND			13		μA
SHDN = GND			0.01	2	μA
Load on V5X = 5mA		5.049	5.100	5.151	V
Load on V5V = 5mA, (Note 2)			90		%
L = 47µH, (Note 2)			11		mA
		90	120		mA
MODE = V _{IN}			550		kHz
MODE = GND			15.62		kHz
•					<u> </u>
Load on V2X = 100µA	•	9.792	10.1	10.608	V
	$MODE = V_{IN}$ $MODE = GND$ $MODE = GND$ $\overline{SHDN} = GND$ $Load on V5X = 5mA$ $Load on V5V = 5mA, (Note 2)$ $L = 47\mu H, (Note 2)$ $MODE = V_{IN}$ $MODE = GND$			Image: Second state of the second	$\begin{tabular}{ c c c c c c c } \hline \bullet & 1.5 & 4.6 \\ \hline MODE = V_{IN} & 75 & 130 \\ \hline MODE = GND & 80 \\ \hline MODE = GND & 30 & 50 \\ \hline MODE = GND & 13 \\ \hline SHDN = GND & 0.01 & 2 \\ \hline \\$



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ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. V_{IN} = 3.6V, V_{OUT} = 5.2V unless otherwise noted.

PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V3X Output Voltage	Load on V3X = 100µA	•	14.688	15.2	15.912	V
V2X Efficiency	Load on V2X = 100µA, (Note 2)			90		%
V3X Efficiency	Load on V3X = 100µA, (Note 2)			80		%
Output Impedance V2X, V3X	Flying Capacitors = 0.1µF			1		kΩ
V _{NEG} Output Voltage	Load on V _{NEG} = 100µA, V _{INV} = V2X	•	-10.608	-10.1	-9.792	V
V _{NEG} Efficiency	Load on V _{NEG} = 100µA (Note 2)			80		%
Output Impedance V _{NEG}	Flying Capacitor = 0.1µF			1		kΩ
Switching Frequency Charge Pumps	MODE = V _{IN}			62.5		kHz
Switching Frequency Charge Pumps	MODE = GND			3.75		kHz
V _{NEG} to V3X Delay	(Note 3)		3	4	10	ms
Logic Inputs						
SHDN Pin Threshold		•	0.4	0.77	1.2	V
MODE Pin Threshold				1.6		V

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

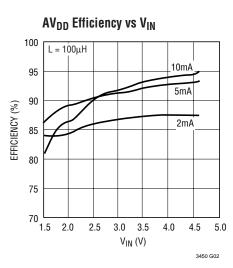
Note 2: Specification is guaranteed by design and not 100% tested in production.

Note 3: Measured from point at which $V_{\text{NEG}}\xspace$ crosses –5V to point at which C2⁻ starts switching.

Note 4: The LTC3450E is guaranteed to meet performance specifications from 0°C to 70°C. Specifications over the -40°C to 85°C operating temperature range are assured by design, characterization and correlation with statistical process controls.

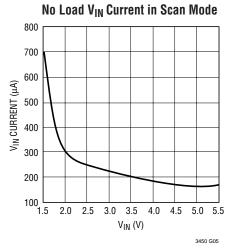
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TYPICAL PERFORMANCE CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

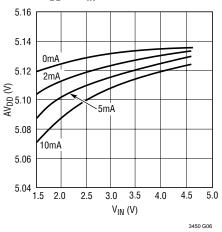


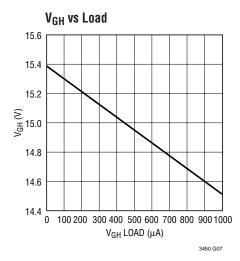
AV_{DD} Efficiency vs V_{IN} 100 $L = 47\mu H$ 95 10mA 90 EFFICIENCY (%) 5mA 85 2mA 80 75 70 1.5 2.0 2.5 3.0 3.5 4.0 4.5 5.0 V_{IN} (V) 3450 G03

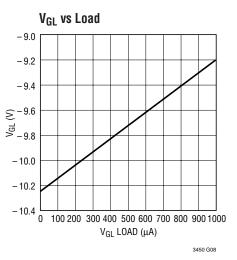
No Load V_{IN} Current in Blank Mode 100 90 80 70 V_{IN} CURRENT (µA) 60 50 40 30 20 10 0 ∟ 1.5 2.0 2.5 3.0 3.5 4.0 4.5 5.0 5.5 V_{IN} (V) 3450 G04



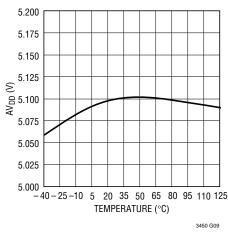
AV_{DD} vs V_{IN} and Load







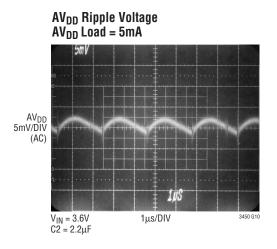
AV_{DD} vs Temperature Figure 1 Circuit, 1mA Load



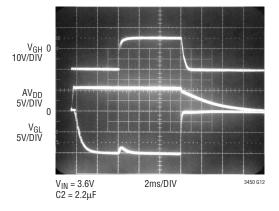
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TYPICAL PERFORMANCE CHARACTERISTICS

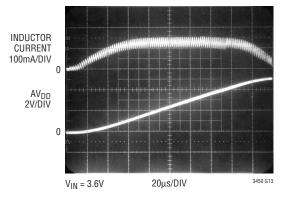


 $AV_{DD},\,V_{GL},\,V_{GH}$ Turn-On and Turn-Off Sequence



AV_{DD} COMP 100mV/DIV (AC) $AV_{DD} LOAD 5mA/DIV 5mA/DIV 1mA$ $V_{IN} = 3.6V C2 = 2.2\mu F$

AV_{DD} Turn-On Showing Inrush Current Limiting





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PIN FUNCTIONS

C3⁺ (Pin 1): Charge Pump Inverter Flying Capacitor Positive Node. The charge pump inverter flying capacitor is connected between C3⁺ and C3⁻. The voltage on C3⁺ will alternate between GND and V_{INV} at an approximate 50% duty cycle while the inverting charge pump is operating. Use a 10nF or larger X5R type ceramic capacitor for best results.

C3⁻ (**Pin 2**): Charge Pump Inverter Flying Capacitor Negative Node. The charge pump inverter flying capacitor is connected between C3⁺ and C3⁻. The voltage on C3⁻ will alternate between GND and V_{NEG} at an approximate 50% duty cycle while the inverting charge pump is operating. Use a 10nF or larger X5R type ceramic capacitor for best results.

 V_{NEG} (Pin 3): Charge Pump Inverter Output. V_{NEG} can be either -5V or -10V depending on where V_{INV} is connected. V_{NEG} should be bypassed to GND with at $0.1\mu F$ or larger X5R type ceramic capacitor. V_{NEG} can also be configured for -15V with two external low current Schottky diodes (see Applications section).

MODE (Pin 4): Drive MODE high to force the LTC3450 into high power (scan) mode. Drive MODE low to force the LTC3450 into low power (blank) mode. The output voltages remain active with the MODE pin driven low but with reduced output current capability. MODE must be pulled up to V_{IN} or higher on initial application of power in order for proper initialization to occur.

SHDN (Pin 5): Master Shutdown Input for the LTC3450. Driving SHDN low disables all IC functions and reduces quiescent current from the battery to less than 2μ A. Each generated output voltage is actively discharged to GND in shutdown through internal pull down devices. An optional RC network on SHDN provides a slower ramp up of the boost converter inductor current during startup (soft-start).

 V_{IN} (Pin 6): Input Supply to the LTC3450. Connect V_{IN} to a voltage source between 1.5V and 4.6V. Bypass V_{IN} to GND with a 2.2µF X5R ceramic capacitor.

 V_{OUT} (Pin 7): Main 5.1V Output of the Boost Regulator and Input to the Voltage Doubler Stage. Bypass V_{OUT} with a low ESR, ESL ceramic capacitor (X5R type) between 2.2µF and 10µF. **SW (Pin 8):** Switch Pin. Connect the inductor between SW and V_{IN} . Keep PCB trace lengths as short and wide as possible to reduce EMI and voltage overshoot. If the inductor current falls to zero, the internal P-channel MOSFET synchronous rectifier is turned off to prevent reverse charging of the inductor and an internal switch connects SW to V_{IN} to reduce EMI.

GND (Pin 9): Signal and Power Ground for the LTC3450. Provide a short direct PCB path between GND and the (–) side of the output filter capacitor(s) on V_{OUT} , V2X, V3X and V_{NEG} .

C1⁻ (Pin 10): Charge Pump Doubler Flying Capacitor Negative Node. The charge pump doubler flying capacitor is connected between C1⁺ and C1⁻. The voltage on C1⁻ will alternate between GND and V_{OUT} at an approximate 50% duty cycle while the charge pump is operating. Use a 10nF or larger X5R type ceramic capacitor for best results.

C1⁺ (Pin 11): Charge Pump Doubler Flying Capacitor Positive Node. The charge pump doubler flying capacitor is connected between C1⁺ and C1⁻. The voltage on C1⁺ will alternate between V_{OUT} and V2X at an approximate 50% duty cycle while the charge pump is operating. Use a 10nF or larger X5R type ceramic capacitor for best results.

V2X (Pin 12): Charge Pump Doubler Output. This output is 10.2V (nom) at no load and is capable of delivering up to 500 μ A to a load. V2X should be bypassed to GND with a 0.47 μ F X5R type ceramic capacitor.

C2⁻ (Pin 13): Charge Pump Tripler Flying Capacitor Negative Node. The charge pump tripler flying capacitor is connected between C2⁺ and C2⁻. The voltage on C2⁻ will alternate between GND and V_{OUT} at an approximate 50% duty cycle while the charge pump is operating. Use a 10nF or larger X5R type ceramic capacitor for best results.

C2+ (Pin 14): Charge Pump Tripler Flying Capacitor Positive Node. The charge pump tripler flying capacitor is connected between C2⁺ and C2⁻. The voltage on C2⁺ will alternate between V2X and V3X at an approximate 50% duty cycle while the charge pump is operating. Use a 10nF or larger X5R type ceramic capacitor for best results.

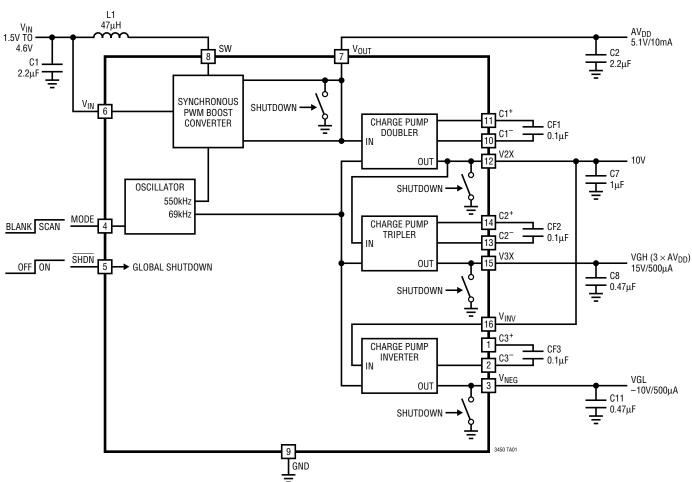


PIN FUNCTIONS

V3X (Pin 15): Charge Pump Tripler Output. This output is 15.3V (nom) at no load and is capable of delivering up to 500μ A to a load. V3X should be bypassed to GND with a 0.1 μ F X5R type ceramic capacitor.

 V_{INV} (Pin 16): Positive Voltage Input for the Charge Pump Inverter. The charge pump inverter will generate a negative voltage corresponding to the voltage applied to V_{INV} . Connecting V_{INV} to 5V or 10V will generate -5V or -10V respectively on $V_{NEG}.$ See Applications section for -15V generation.

Exposed Pad (Pin 17): The exposed pad must be connected to V_{NEG} (Pin 3) on the PCB. *Do not connect the exposed pad to GND.*



BLOCK DIAGRAM

OPERATION

The LTC3450 is a highly integrated power converter intended for small TFT-LCD display modules. A fixed frequency, synchronous PWM boost regulator generates a low noise 5.1V, 10mA bias at greater than 90% efficiency from an input voltage of 1.5V to 4.6V. Three charge pump converters use the 5.1V output to generate 10V, 15V and -5V, -10V or -15V at load currents up to 500µA. Each converter is frequency synchronized to the main 500kHz (nominal) boost converter. The generated output voltages are internally sequenced to insure proper initialization of the LCD panel. A digital shutdown input rapidly discharges each generated output voltage to provide a near instantaneous turn-off of the LCD display.

Boost Converter

The synchronous boost converter utilizes current mode control and includes internally set control loop and slope compensation for optimized performance and simple design. Only three external components are required to complete the design of the 5.1V, 10mA boost converter. The high operation frequency produces very low output ripple and allows the use of small low profile inductors and tiny external ceramic capacitors. The boost converter also disconnects its output from V_{IN} during shutdown to avoid loading the input power source. Softstart produces a controlled ramp of the converter input current during startup, reducing the burden on the input power source. Very low operating quiescent current and synchronous operation allow for greater than 90% conversion efficiency.

The MODE input reduces the boost converter operating frequency by approximately 8x when driven high and reduces the output power capability of the boost converter. MODE is asserted when the polysilicon TFT-LCD display is in its extremely low power blank condition. The

boost converter further reduces its quiescent current in this mode, delivering both lower input (battery) current drain and low noise operation.

Charge Pumps

The LTC3450 includes three separate charge pump converters which generate 10V, 15V and either -5V, -10V or -15V. Each output can deliver a maximum of 500μ A. The charge pumps feature fixed frequency, open-loop operation for high efficiency and lowest noise performance. The charge pump converters operate at 1/8 the boost converter frequency and include internal charge transfer switches. Thus, each charge pump requires only two small external capacitors, one to transfer charge, and one for filtering. Similar to the boost converter, the charge pumps operating frequency reduces to approximately 4kHz in blank mode, maintaining low noise operation but at reduced output current capability.

Output Sequencing

Refer to the following text and Figure 1 for the LTC3450 power-up sequence. When input power is applied, the boost converter initializes and charges its output towards the final value of 5.1V. When the boost converter output reaches approximately 90% of its final value (4.5V), an internal 5V OK signal is asserted which allows the charge pump doubler to begin operation toward its final goal of 10V. Approximately 1ms later, the charge pump inverter begins operation toward its final goal of either -5V or -10V depending on the connection of the V_{INV} input. When the -5V or -10V output (V_{NEG}) reaches approximately 50% of its final value, a 4ms (nominal) timeout period begins. At the conclusion of the 4ms timeout period, the charge pump tripler is allowed to begin operation, which will eventually charge V3X to 15V (nominal).

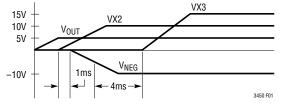


Figure 1. Output Sequencing



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APPLICATIONS INFORMATION

Inductor Selection

Inductors in the range of 47μ H to 100μ H with saturation current (I_{SAT}) ratings of at least 150mA are recommended for use with the LTC3450. Ferrite core materials are strongly recommended for their superior high frequency performance characteristics. A bobbin or toroid type core will reduce radiated noise. Inductors meeting these requirements are listed in Table 1.

PART	L	MAX DCR	HEIGHT	VENDOR		
NUMBER	(µH)	(Ω)	(mm)			
CLQ4D10-470 CLQ4D10-101 CMD4D08-470	47 100 47	1.28 3.15 1.6	1.2 1.0	Sumida (847) 956-0666 www.sumida.com		
D01606-473 D01606-104 DT1608-473 DT1608-104	47 100 47 100	1.1 2.3 0.34 1.1	2.0 2.92	Coilcraft (847) 639-6400 www.coilcraft.com		
LQH43MN470J03	47	1.5	2.6	Murata		
LQH43MN101J03	100	2.5		www.murata.com		
DU6629-470M	47	0.64	2.92	Coev Magnetics		
DU6629-101M	100	1.27		www.circuitprotection.com		

Capacitor Selection

The boost converter requires two capacitors. The input capacitor should be an X5R type of at least 1μ F. The V_{OUT} capacitor should also be an X5R type between 2.2 μ F and 10μ F. A larger capacitor (10μ F) should be used if lower output ripple is desired or the output load required is close to the 10mA maximum.

The charge pumps require flying capacitors of at least 0.1 μ F to obtain specified performance. Ceramic X5R types are strongly recommended for their low ESR and ESL and capacitance versus bias voltage stability. The filter capacitor on V2X should be at least 0.1 μ F. A 0.47 μ F or larger capacitor on V2X is recommended if V_{INV} is connected to V2X. The filter capacitors on V3X and V_{NEG} should be 0.1 μ F or larger. Please be certain that the capacitors used are rated for the maximum voltage with adequate safety margin. Refer to Table 2 for a listing of capacitor vendors.

Table 2. Capa	citor Vendor	Information
---------------	--------------	-------------

Supplier	Phone	Website
AVX	(803) 448-9411	www.avxcorp.com
Murata	(714) 852-2001	www.murata.com
Taiyo Yuden	(408) 573-4150	www.t-yuden.com



Soft-start operation provides a gradual increase in the current drawn from the input power source (usually a battery) during initial startup of the LTC3450, eliminating the inrush current which is typical in most boost converters. This reduces stress on the input power source, boost inductor and output capacitor, reduces voltage sag on the battery and increases battery life. The rate at which the input current will increase is set by two external components (R_{SS} and C_{SS}) connected to SHDN (refer to Figure 2). Upon initial application of power or release of a pull down switch on SHDN, the voltage on SHDN will increase relative to the R • C time constant or R_{SS} • C_{SS}. After one time constant SHDN will rise to approximately 63.2% of the voltage on V_{IN}. From 0V to approximately 0.65V on SHDN, no switching will occur because the shutdown threshold is 0.65V (typ). From 0.65V to 1V the maximum switch pin current capability of the LTC3450 will gradually increase from near zero to the maximum current limit. An Rss in the range of $1M\Omega$ to $10M\Omega$ is recommended. If SHDN is driven high with a logic signal, the input current will gradually increase to its maximum value in approximately 50µs.

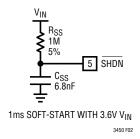


Figure 2. Soft-Start Component Configuration

Printed Circuit Board Layout Guidelines

High speed operation of the LTC3450 demands careful attention to PCB layout. You will not get advertised performance with careless layout. Figure 3 shows the recommended component placement for a single layer PCB. A multilayer board with a separate ground plane is ideal but not absolutely necessary.

APPLICATIONS INFORMATION

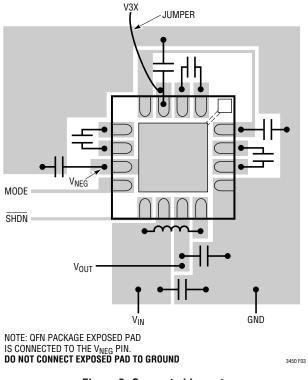
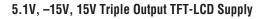
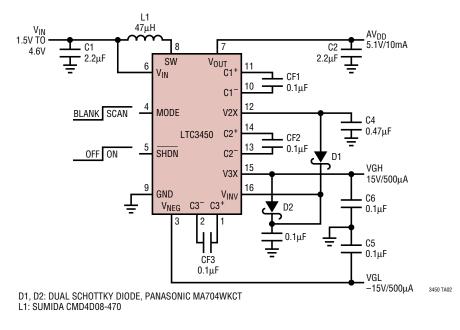


Figure 3. Suggested Layout

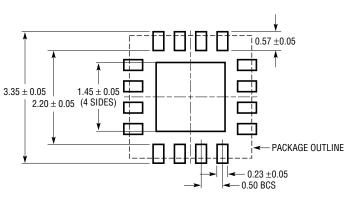
TYPICAL APPLICATION



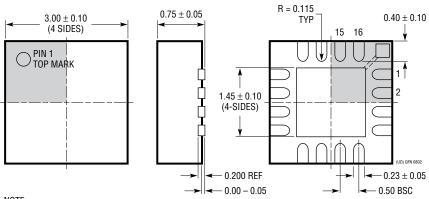


3450f

PACKAGE DESCRIPTION



RECOMMENDED SOLDER PAD PITCH AND DIMENSIONS



BOTTOM VIEW-EXPOSED PAD

NOTE:

1. DRAWING CONFORMS TO JEDEC PACKAGE OUTLINE MO-220 VARIATION (WEED-2)

UD Package 16-Lead Plastic QFN ($3mm \times 3mm$) (Reference LTC DWG # 05-08-1691)

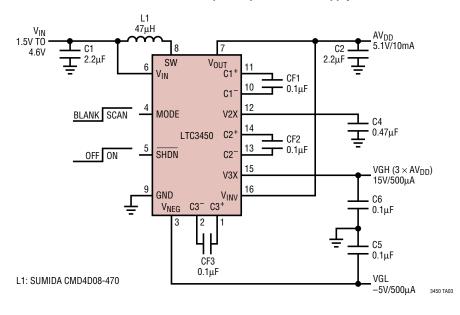
2. ALL DIMENSIONS ARE IN MILLIMETERS

3. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE

MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE 4. EXPOSED PAD SHALL BE SOLDER PLATED



TYPICAL APPLICATION



5.1V, -5V, 15V Triple Output TFT-LCD Supply

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1310	1.5A I _{SW} , 4.5MHz, High Efficiency Step-Up DC/DC Converter	V_{IN} : 2.75V to 18V, V_{OUT} = 35V, I_{Q} = 12mA, I_{SD} = <1 μA MSE Package
LT1613	550mA I _{SW} , 1.4MHz, High Efficiency Step-Up DC/DC Converter	V_{IN} : 0.9V to 10V, V_{OUT} = 34V, I_Q = 3mA, I_{SD} = <1 μA ThinSOT Package
LT1615/LT1615-1	300mA/80mA I _{SW} , Constant Off-Time, High Efficiency Step-Up DC/DC Converter	V_{IN} : 1.2V to 15V, V_{OUT} = 34V, I_Q = 20µA, I_{SD} = <1µA ThinSOT Package
LT1940	Dual Output 1.4A I _{OUT} , Constant 1.1MHz, High Efficiency Step-Down DC/DC Converter	V_{IN} : 3V to 25V, V_{OUT} (MIN) $=$ 1.2V, I_Q = 2.5mA, I_{SD} = <1 μA TSSOP-16E Package
LT1944	Dual Output 350mA I _{SW} , Constant Off-Time, High Efficiency Step-Up DC/DC Converter	V_{IN} : 1.2V to 15V, V_{OUT} = 34V, I_Q = 20µA, I_{SD} = <1µA MS Package
LT1944-1	Dual Output 150mA I _{SW} , Constant Off-Time, High Efficiency Step-Up DC/DC Converter	V_{IN} : 1.2V to 15V, V_{OUT} = 34V, I_{Q} = 20µA, I_{SD} = <1µA MS Package
LT1945	Dual Output, Pos/Neg, 350mA I _{SW} , Constant Off-Time, High Efficiency Step-Up DC/DC Converter	V_{IN} : 1.2V to 15V, V_{OUT} = $\pm 34V,$ I_Q = 20µA, I_{SD} = <1µA MS Package
LT1946/LT1946A	1.5A I _{SW} , 1.2MHz/2.7MHz, High Efficiency Step-Up DC/DC Converter	V_{IN} : 2.45V to 16V, V_{OUT} = 34V, I_Q = 3.2mA, I_{SD} = <1 μA MS8 Package
LT1947	Triple Output (for TFT-LCD) 1.1A I _{SW} , 3MHz High Efficiency Step-Up DC/DC Converter	V_{IN} : 2.7V to 8V, V_{OUT} = 34V, I_Q = 9.5mA, I_{SD} = <1 μA MS Package
LT1949/LT1949-1	550mA I _{SW} , 600kHz/1.1MHz, High Efficiency Step-Up DC/DC Converter	V_{IN} : 1.5V to 12V, V_{OUT} = 28V, I_{Q} = 4.5mA, I_{SD} = <25 μA S8, MS8 Packages
LTC3400/LTC3400B	600mA I _{SW} , 1.2MHz, Synchronous Step-Up DC/DC Converter	V_{IN} : 0.85V to 5V, V_{OUT} = 5V, I_{Q} = 19µA/300µA, I_{SD} = <1µA ThinSOT Package
LTC3401	1A I _{SW} , 3MHz, Synchronous Step-Up DC/DC Converter	V_{IN} : 0.5V to 5V, V_{OUT} = 5V, I_{Q} = 38µA, I_{SD} = <1µA, MS Package
LTC3402	2A I _{SW} , 3MHz, Synchronous Step-Up DC/DC Converter	V_{IN} : 0.5V to 5V, V_{OUT} = 5V, I_Q = 38 μ A, I_{SD} = <1 μ A, MS Package



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